| | Туре | L # | Hits | Search Text | DBs | Time | Stamp | | Er ro rs |
|---|------|-----|-------|--|-----------------------|-----------------|-------|--|----------------|
| 1 | BRS | L1 | 13 | with deposit\$4 and source with | FDO. TDO. | 2005/1 17:52 | 11/26 | | |
| 2 | BRS | L2 | 21 | nanowire near (deposit\$4 or flow\$ or plac\$4) and source with drain and nanowire with channel | IH: D() • . D() • | 2005/1 18:01 | 11/26 | | |
| 3 | BRS | L3 | 14 | semiconduct\$4 with nanowire with (deposit\$4 or flow\$) and source with drain and nanowire with channel | IH: D() • . D() • | 2005/1 18:13 | L1/26 | | |
| 4 | BRS | L4 | IX () | ISEMICONOLICES4 | IH: D() • . D() • | 2005/1 18:29 | 11/26 | | |

| | Type | L # | Hits | Search Text | DBs | Time | Stamp | Comens ens | De fi | Er ro rs |
|---|------|-----|------|--------------------------------|---|-----------------|-------|---------------|----------|----------------|
| 5 | BRS | L5 | 7 | with nanowire with (deposit\$4 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | 2005/1 18:29 | 1/26 | | | |